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Step by step with ATLAS Silvaco

Presentation · April 2018

DOI: 10.13140/RG.2.2.19564.46722

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Getting Started with Atlas

Ali Abdolazadeh Ziabari

Atlas is a physically-based **two** and **three dimensional** device simulator. It predicts the **electrical behavior** of specified semiconductor structures and provides insight into the internal physical mechanisms associated with device operation.

1-Running Atlas inside Deckbuild

Each Atlas run inside DeckBuild should start with the line:

```
go atlas
```

2-The Order of Atlas Commands

<i>Group</i>		<i>Statements</i>
1. Structure Specification	————	MESH REGION ELECTRODE DOPING
2. Material Models Specification	————	MATERIAL MODELS CONTACT INTERFACE
3. Numerical Method Selection	————	METHOD
4. Solution Specification	————	LOG SOLVE LOAD SAVE
5. Results Analysis	————	EXTRACT TONYLOT

3- Using The Command Language to Define a Structure

You must first define a mesh. The first statement **must be**:

```
MESH SPACE.MULT=<VALUE>
```

This is followed by a series of `X.MESH` and `Y.MESH` statements.

```
X.MESH LOCATION=<VALUE> SPACING=<VALUE>
```

```
.
```

```
Y.MESH LOCATION=<VALUE> SPACING=<VALUE>
```

```
.
```

The `SPACE.MULT` parameter value is used as a scaling factor for the mesh created by the `X.MESH` and `Y.MESH` statements. The default value is 1. Values greater than 1 will create a globally coarser mesh for fast simulation. Values less than 1 will create a globally finer mesh for increased accuracy.

EXAMPLE: a simple mesh

```
go atlas
```

```
mesh space.mult=1
```

```
x.m l=-1 s=0.01
```

```
x.m l=0 s=0.05
```

```
x.m l=1 s=0.01
```

```
y.m l=0 s=1
```

```
y.m l=2 s=0.02
```

```
save outf=simple.str
```

```
tonyplot simple.str
```

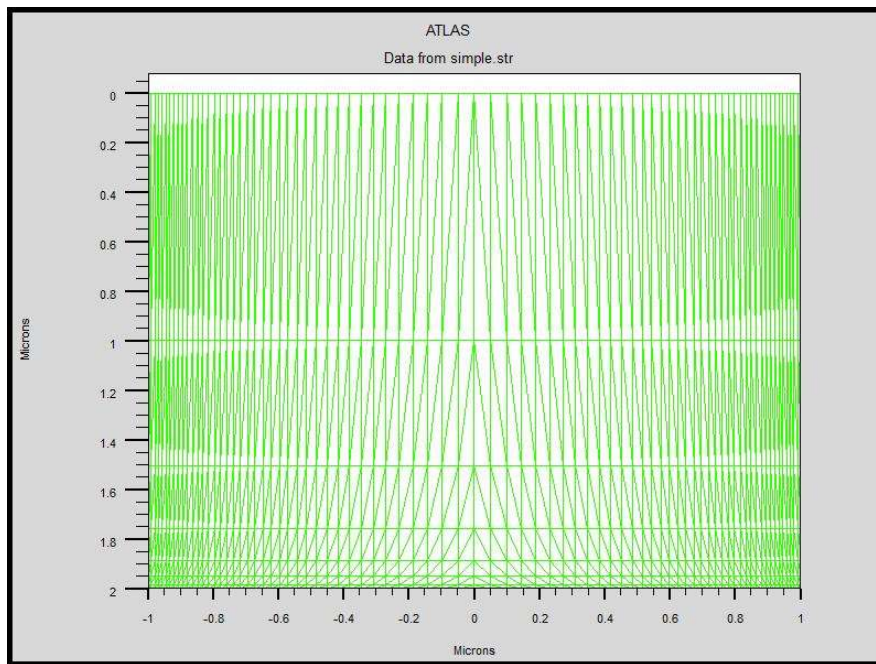


Fig.1. A simple structure by Atlas.

After an initial mesh has been defined, you can remove grid lines in specified regions. This is typically done in regions of the device where a coarse grid is expected to be sufficient such as the substrate. The removal of grid lines is accomplished using the **ELIMINATE** statement. The **ELIMINATE** statement removes every second mesh line in the specified direction from within a specified rectangle.

EXAMPLE:

```
go atlas

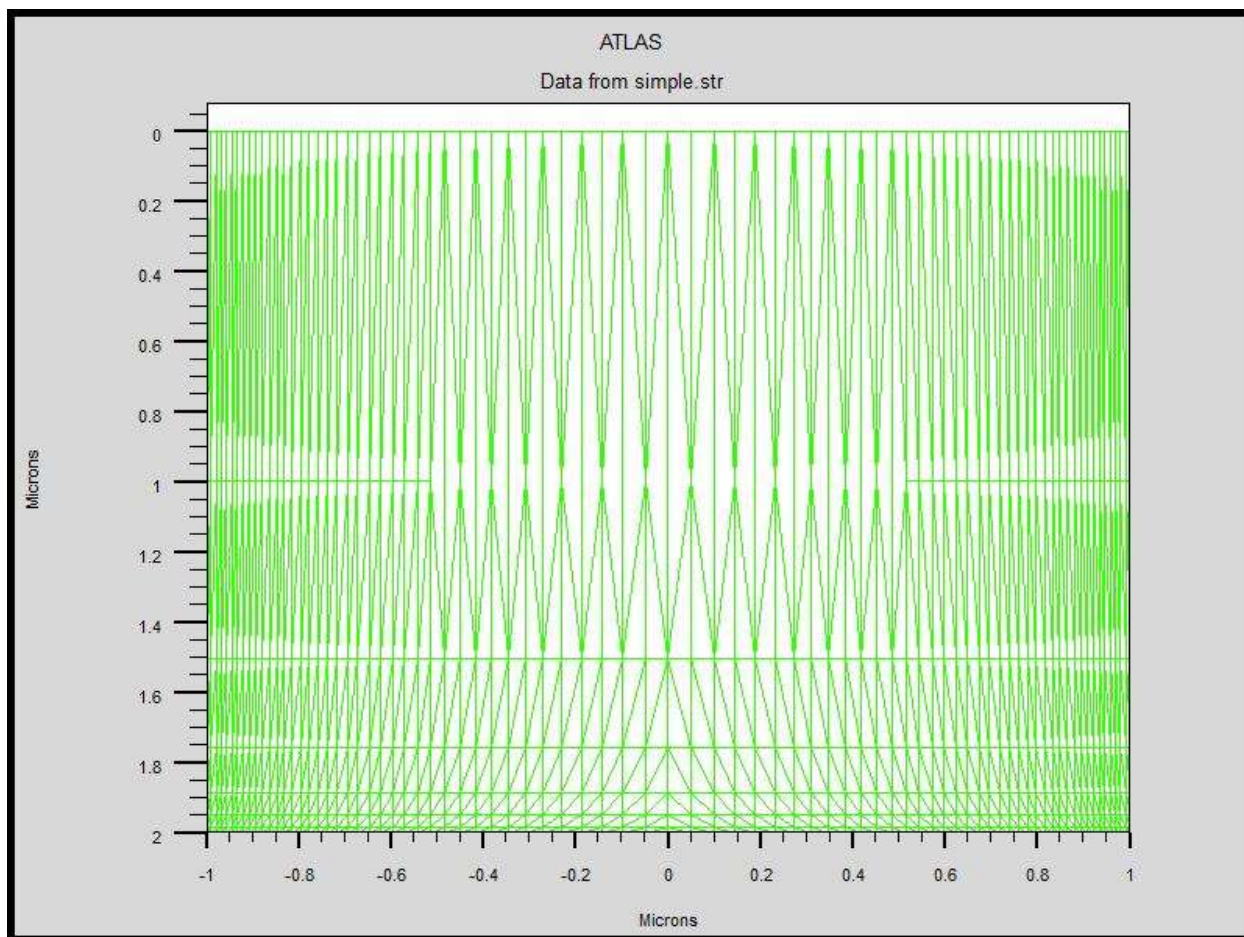
mesh space.mult=1

x.m l=-1 s=0.01
x.m l=0 s=0.05
x.m l=1 s=0.01

y.m l=0 s=1
y.m l=2 s=0.02

eliminate columns x.min=-0.5 x.max=0.5 y.min=0 y.max=1

save outf=simple.str
tonyplot simple.str
```



4-Specifying Regions and Materials

REGION number=<integer> <material_type> <position parameters>

Example:

```
go atlas

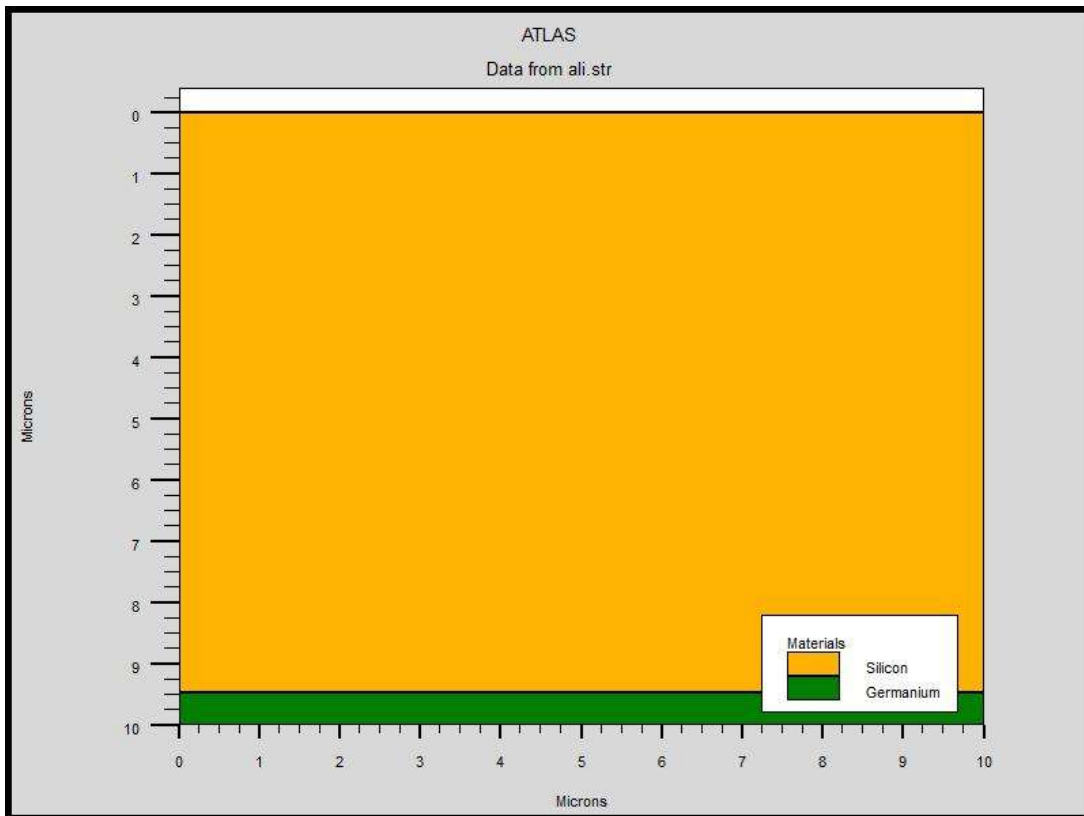
mesh space.mult=1.0

x.mesh loc=0.0  spacing=2.5
x.mesh loc=10.0 spacing=2.5

y.mesh loc=0.0  spacing=0.05
y.mesh loc=5.0  spacing=0.2
y.mesh loc=10   spacing=0.05

region num=1 material=Silicon  y.max=9.5
region num=2 material=Ge       y.min=9.5 y.max=10

save outf=ali.str
tonyplot ali.str
```



5- Specifying Electrodes

Once you have specified the regions and materials, define at least one electrode that contacts a semiconductor material. This is done with the `ELECTRODE` statement:

```
ELECTRODE NAME=<electrode name> <position_parameters>
```

You can **specify** up to **50 electrodes**.

Shortcuts: If no Y coordinate parameters are specified, the electrode is assumed to be located on the top of the structure. You also can use the `RIGHT`, `LEFT`, `TOP`, and `BOTTOM` parameters to define the location. For **example**:

```
ELECTRODE NAME=SOURCE LEFT LENGTH=0.5
```

specifies the source electrode starts at the top left corner of the structure and extends to the right for the distance `LENGTH`.

Example

```
go atlas

mesh space.mult=1

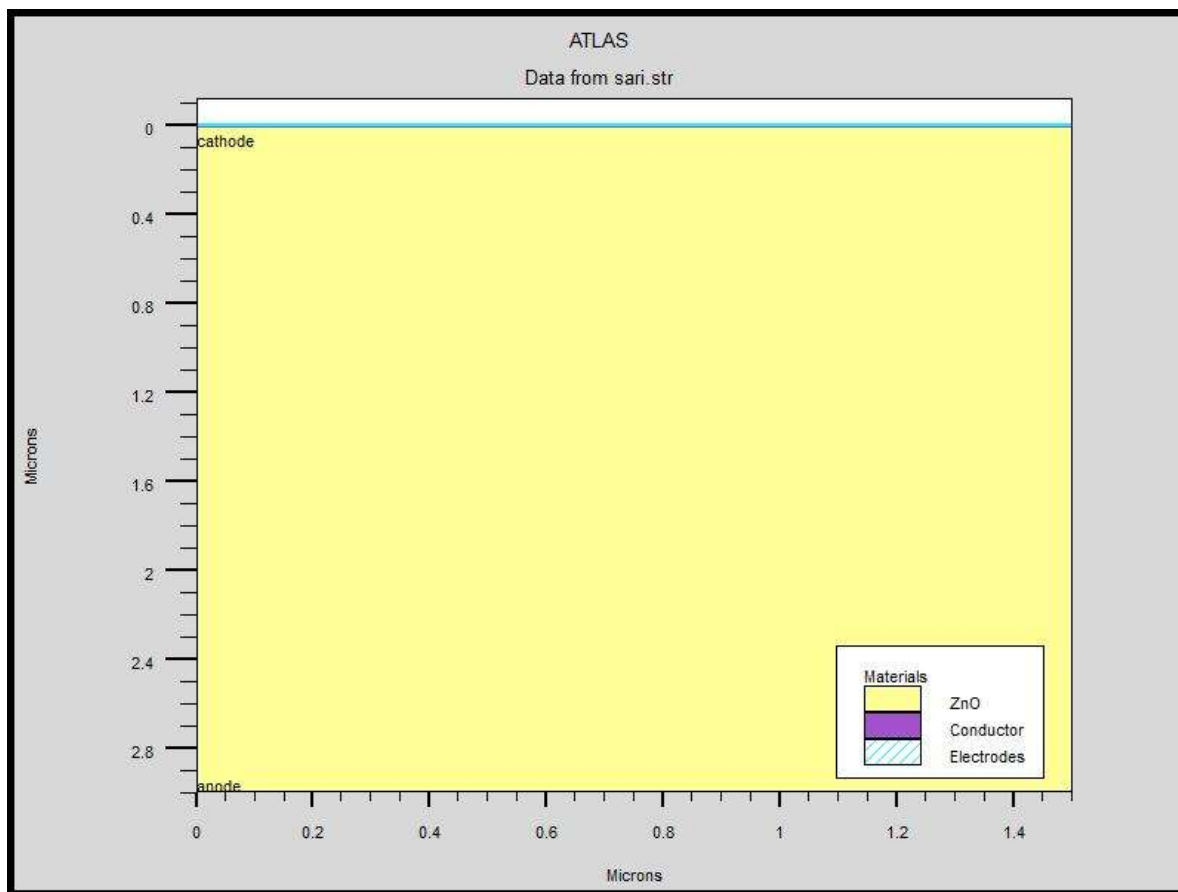
x.m l=0 s=0.5
x.m l=1.5 s=0.2

y.m l=0 s=0.2
y.m l=3 s=0.1

region num=1 mat=zno y.min=0 y.max=3

electrode name=cathode top length=2
electrode name=anode bottom length=2

save outf=sari.str
tonyplot sari.str
```



6- Specifying Doping

You specify the doping using the `DOPING` statement. For example:

```
DOPING <distribution_type> <dopant_type> <position_parameters>
```

Analytical doping profiles can have **uniform**, **Gaussian**, or **complementary error function** forms. The parameters defining the analytical distribution are specified in the `DOPING` statement.

Example

```
go atlas

mesh space.mult=1

x.m l=0 s=0.5
x.m l=1.5 s=0.2

y.m l=0 s=0.2
y.m l=3 s=0.1

region num=1 mat=zno y.min=0 y.max=2
region num=2 mat=al2o3 y.min=2

electrode name=cathode top length=2
electrode name=anode bottom length=2

doping uniform concentration=1e18 n.type region=1
doping gaussian concentration=1e16 characteristic=0.05 p.type x.left=0
x.right=1.5 peak=0.75

save outf=sari.str
tonyplot sari.str
```

